

## 4GBJ10005 THRU 4GBJ1010

### **GLASS PASSIVATED BRIDGE RECTIFIER**

Reverse Voltage - 50 to 1000 Volts Forward Current - 10.0 Ampere

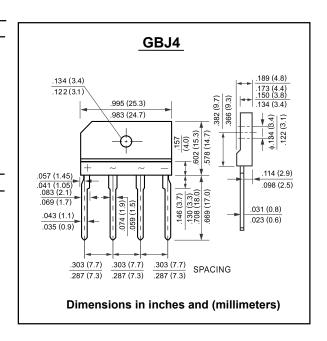
#### **FEATURES**

- Glass passivated chip junction
- Reliable low cost construction utilizing molded plastic technique
- Ideal for printed circuit board
- Low reverse leakage current
- Low forward voltage drop
- High surge current capabiliy

#### **MECHANICAL DATA**

- Case:Molded plastic, GBJ
- Terminals: Terminals: Leads solderable per MIL-STD-202 method 208 guaranteed
- Epoxy: UL 94V-0 rate flame retardant
- Mounting Position: Any





#### Maximum Ratings and Electrical Characteristics @TA=25°C unless otherwise specified

Single Phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

| Characteristic  | Symbol             | 4GBJ<br>10005 | 4GBJ<br>1001 | 4GBJ<br>1002 | 4GBJ<br>1004 | 4GBJ<br>1006 | 4GBJ<br>1008 | 4GBJ<br>1010 | Unit |
|---|--------------------|---------------|--------------|--------------|--------------|--------------|--------------|--------------|------|
| Peak Repetitive Reverse Voltage<br>Working Peak Reverse Voltage<br>DC Blocking Voltage                                | VRRM<br>VRWM<br>VR | 50            | 100          | 200          | 400          | 600          | 800          | 1000         | V    |
| RMS Reverse Voltage   | VR(RMS)            | 35            | 70           | 140          | 280          | 420          | 560          | 700          | ٧    |
| Average Rectified Output Current @T <sub>C</sub> = 115°C (Note 1)   | lo                 | 10            |              |              |              |              |              |              | Α    |
| Non-Repetitive Peak Forward Surge Current<br>8.3ms Single half sine-wave superimposed on<br>rated load (JEDEC Method) | IFSM               | 220           |              |              |              |              |              |              | А    |
| Forward Voltage per diode @I <sub>F</sub> = 5.0A  | VFM                | 1.1           |              |              |              |              |              |              | V    |
|   | lR                 | 10<br>500     |              |              |              |              |              |              | μΑ   |
| Typical Thermal Resistance per leg (Note 2)   | R ⊕ JA             | 26            |              |              |              |              |              |              | °C/W |
| Typical Thermal Resistance per leg (Note 1)   | R⊕JC               | 1.9           |              |              |              |              |              |              | °C/W |
| Operating and Storage Temperature Range   | Tj, Tstg           | -55 to +150   |              |              |              |              |              |              | °C   |

- Note: 1. Device mounted on 100 x 100 x 1.6mm thick Al plate heatsink.
  - 2. Device mounted on P.C.B. without heatsink.



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## **RATINGS AND CHARACTERISTIC CURVES**

